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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SJ598

SWITCHING P-CHANNEL POWER MOS FET

DESCRIPTION

The 2SJ598 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

• Low on-state resistance:

 $R_{DS(on)1} = 130~m\Omega~MAX.~(V_{GS} = -10~V,~I_{D} = -6~A)$

 $R_{DS(on)2} = 190 \text{ m}\Omega \text{ MAX.} (V_{GS} = -4.0 \text{ V}, I_{D} = -6 \text{ A})$

- Low Ciss: Ciss = 720 pF TYP.
- Built-in gate protection diode
- TO-251/TO-252 package

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SJ598	TO-251 (MP-3)		
2SJ598-Z	TO-252 (MP-3Z)		

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	Voss	-60	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)} ∓12		Α
Drain Current (pulse) Note1	ID(pulse)	∓30	Α
Total Power Dissipation (Tc = 25°C)	PT	23	W
Total Power Dissipation (T _A = 25°C)	PT	1.0	W
Channel Temperature	T_ch	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	-12	Α
Single Avalanche Energy Note2	Eas	14.4	mJ

(TO-251)



(TO-252)



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = -30 V, R_G = 25 Ω , V_{GS} = -20 \rightarrow 0 V

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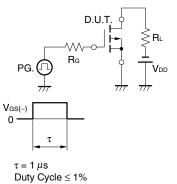
ELECTRICAL CHARACTERISTICS (TA = 25°C)

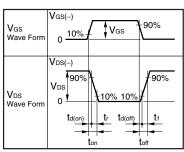
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -60 V, V _{GS} = 0 V			-10	μА
Gate Leakage Current	Igss	$V_{GS} = \mp 16 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μА
Gate Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.5	-2.0	-2.5	٧
Forward Transfer Admittance	y fs	$V_{DS} = -10 \text{ V}, I_{D} = -6 \text{ A}$	5	11		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = -10 V, ID = -6 A		102	130	mΩ
	RDS(on)2	V _{GS} = -4.0 V, I _D = -6 A		131	190	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		720		pF
Output Capacitance	Coss	V _{GS} = 0 V		150		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		50		pF
Turn-on Delay Time	t d(on)	ID = -6 A		7		ns
Rise Time	tr	V _{GS} = -10 V		4		ns
Turn-off Delay Time	t d(off)	VDD = -30 V		35		ns
Fall Time	t f	$R_G = 0 \Omega$		10		ns
Total Gate Charge	Qg	I _D = -12 A		15		nC
Gate to Source Charge	Qgs	V _{DD} = -48 V		3		nC
Gate to Drain Charge	Q _{GD}	V _{GS} = -10 V		4		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 12 A, VGS = 0 V		0.98		٧
Reverse Recovery Time	trr	IF = 12 A, VGS = 0 V		50		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A /μs		100		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$V_{GS} = -20 \rightarrow 0 \text{ V}$ V_{DD} V_{DD}

TEST CIRCUIT 2 SWITCHING TIME



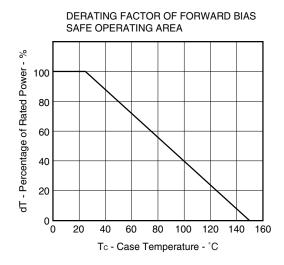


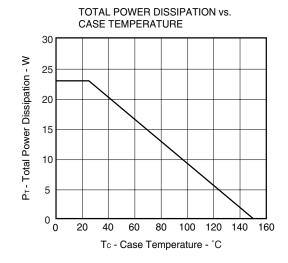
TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c} D.U.T. & \\ \hline \\ I_G = -2 \text{ mA} \\ \hline \\ PG. & \\ \hline \\ \end{array} \begin{array}{c} R_L \\ \hline \\ V_{DD} \end{array}$$

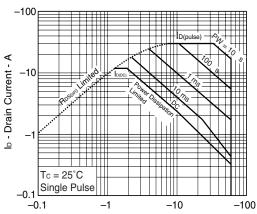


TYPICAL CHARACTERISTICS (TA = 25°C)



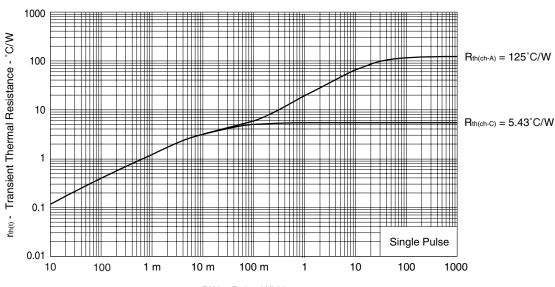


FORWARD BIAS SAFE OPERATING AREA



 $V_{\text{\scriptsize DS}}$ - Drain to Source Voltage - V

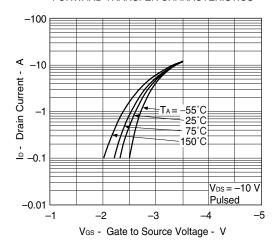
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



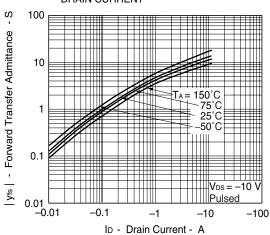
PW - Pulse Width - s

3

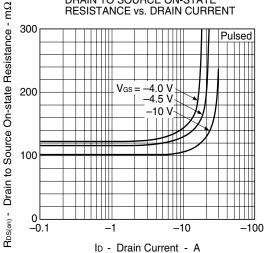
FORWARD TRANSFER CHARACTERISTICS



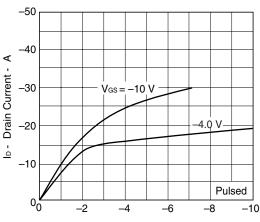
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

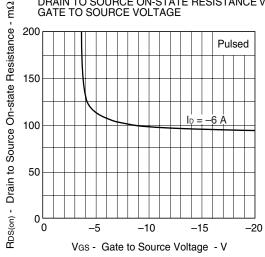


DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

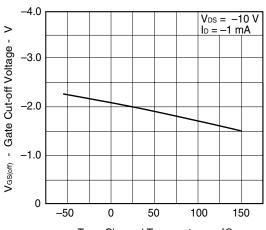


V_{DS} - Drain to Source Voltage - V

DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

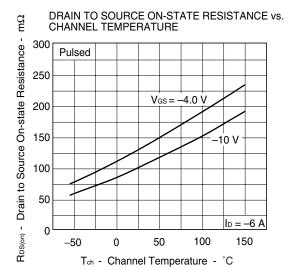


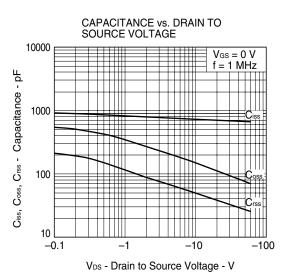
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

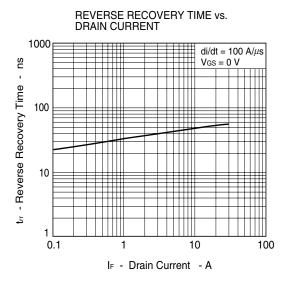


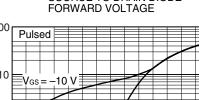
Tch - Channel Temperature - °C



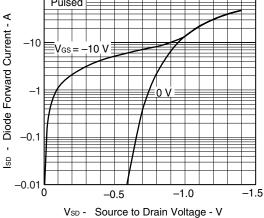




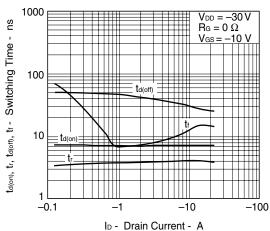




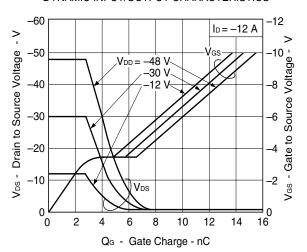
SOURCE TO DRAIN DIODE



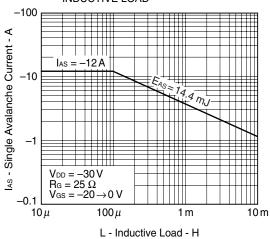
SWITCHING CHARACTERISTICS



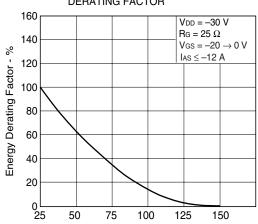
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



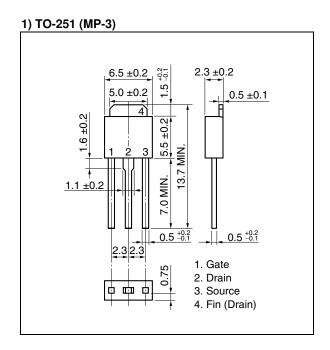
SINGLE AVALANCHE ENERGY DERATING FACTOR

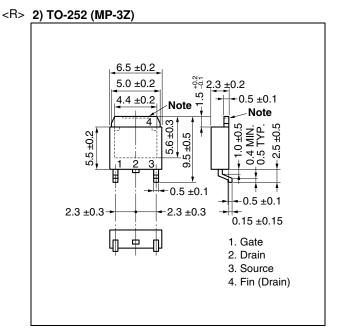


Starting Tch - Starting Channel Temperature - °C



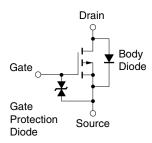
PACKAGE DRAWINGS (Unit: mm)





Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Data Sheet D14656EJ5V0DS 7

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